

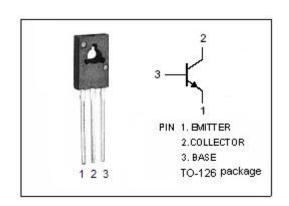
## **ISC Silicon NPN Power Transistor**

## **DESCRIPTION**

- · High Collector-Emitter Breakdown Voltage-V<sub>(BR)CEO</sub>= 200V (Min)
- Complement to Type 2SA1352
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

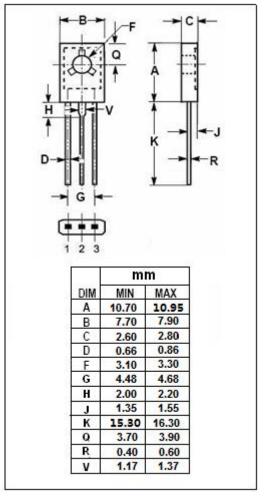
#### **APPLICATIONS**

• Designed for color TV chroma output, high-voltage driver applications.



## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	200	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	200	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
lc	Collector Current-Continuous	0.1	Α	
I <sub>CM</sub>	Collector Current-Peak	0.2	А	
Pc	Collector Power Dissipation @ T <sub>a</sub> =25°C	1.2	W	
	Total Power Dissipation @ T <sub>C</sub> =25°C	5		
Тл	Junction Temperature 150		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	





## isc Silicon NPN Power Transistor

2SC3416

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	Ic= 10 μ A; I <sub>E</sub> = 0	200			V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1mA; R <sub>BE</sub> = ∞	200			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10 μ A; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 20mA; I <sub>B</sub> = 2mA			0.6	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 20mA; I <sub>B</sub> = 2mA			1.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 150V; I <sub>E</sub> = 0			0.1	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V; I <sub>C</sub> = 0			0.1	μА
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10mA ; V <sub>CE</sub> = 40V	40		320	
fτ	Current-Gain—Bandwidth Product	Ic= 10mA ; VcE= 30V		70		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 30V; f= 1.0MHz		1.7		pF

# ♦ h<sub>FE</sub> Classifications

С	D	E	F
40-80	60-120	100-200	160-320

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